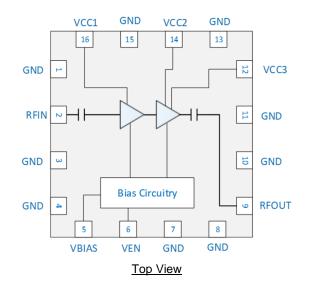
QPA9908 850-960MHz 4 W High-Efficiency Amplifier

Product Overview

The QPA9908 is a high-efficiency, linearizable power amplifier targeting Band 8 small-cell wireless infrastructure systems. The product delivers high efficiency of 36% at +28dBm average output power, while providing excellent DPD linearized ACPR of -48dBc for signal bandwidths of up to 40MHz.

The QPA9908 is housed in a 5x5mm SMT package. It is pin-to-pin compatible to QPA9903 (band 3 high-efficiency small cell PA).







16 Pad 5 x 5 mm Package

Key Features

- 850-960 MHz
- Up to 40MHz IBW capability
- 32.6 dB Gain typical
- 36% PAE at +28 dBm power output
- <-48 dBc ACPR DPD linearized at +28 dBm Pout
- 1.8V logic compatible PA ON/OFF control
- On chip ESD protection

Applications

- 3GPP Band 8 Small Cells
- M-MIMO
- Repeaters / DAS
- Mobile Infrastructure
- General Purpose Wireless

Ordering Information

Part No.	Description
QPA9908TR13	2500 on reel
QPA9908EVB-01	850-960 MHz EVB

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Absolute Maximum Ratings

Parameter	Rating
Storage Temperature	−55 to +125 °C
RF Input Power, Pulsed CW, 50 $\Omega^{(1)}$	+10 dBm
Device Voltage (Vcc)	+5.5 V

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability.

Note:

1. 850-960 MHz, Pulsed CW, 10% duty cycle, 100us period

Recommended Operating Conditions

Parameter	Min	Тур	Max	Units
Device Voltage (Vcc)	+4.75	+5	+5.25	V
TCASE	-40		+85	°C
Tj for >10 ⁶ hours MTTF			+175	°C

Electrical specifications are measured at specified test conditions. Specifications are not guaranteed over all recommended operating conditions.

Electrical Specifications

Parameter	Conditions ⁽¹⁾	Min	Тур	Max	Units
Operational Frequency Range		850		960	MHz
Test Frequency			942		MHz
Gain	Pout = +28 dBm	30	32.6		dB
Input Return Loss			-20		dB
Output P3dB	100 µs/1 ms, 10% duty cycle	+33	+35.5		dBm
Power Added Efficiency (2)	Pout = +28 dBm		36		%
ACPR(Uncorrected) ⁽³⁾	Pout = +28 dBm		-32		dBc
Quiescent Current, Icq	Pins 12, 14 and 16	40	70	100	mA
Total Operating Current	Pins 5, 12, 14 and 16, Pout = +28 dBm		370		mA
Thermal Resistance, θ_{jc}	Junction to case		24		°C/W
V _{EN} High		1.17	1.8	Vcc	V
V _{EN} Low		0	0	0.63	V
2nd Harmonic	Pout = +28 dBm		-40		dBc
3rd Harmonic	Pout = +28 dBm		-50		dBc

Notes:

1. Test conditions unless otherwise noted: All V_{CC} & V_{BIAS} = +5.0 V, V_{EN} = +1.8 V, Temp = +25 °C, 50 Ω system.

2. LTE, 20 MHz E-UTRA Test Model 1.1 or 3.1, PAR = 8.5 dB at 0.01% Probability

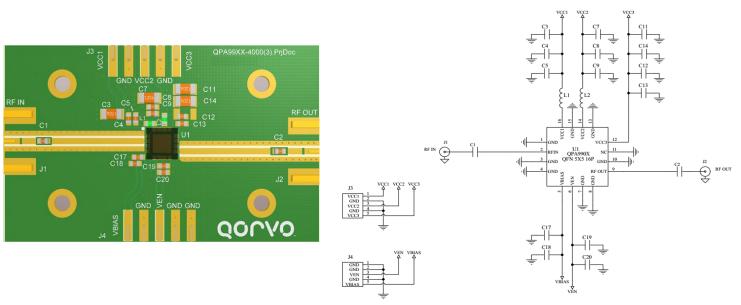
3. LTE, 20 MHz x 2 E-UTRA Test Model 1.1 or 3.1, PAR = 8.5 dB at 0.01% Probability

Power Amplifier Enable Logic Table

Parameter	High Low	
Ven	Power Amplifier ON	Power Amplifier OFF

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850–960 MHz Evaluation Board



Notes:

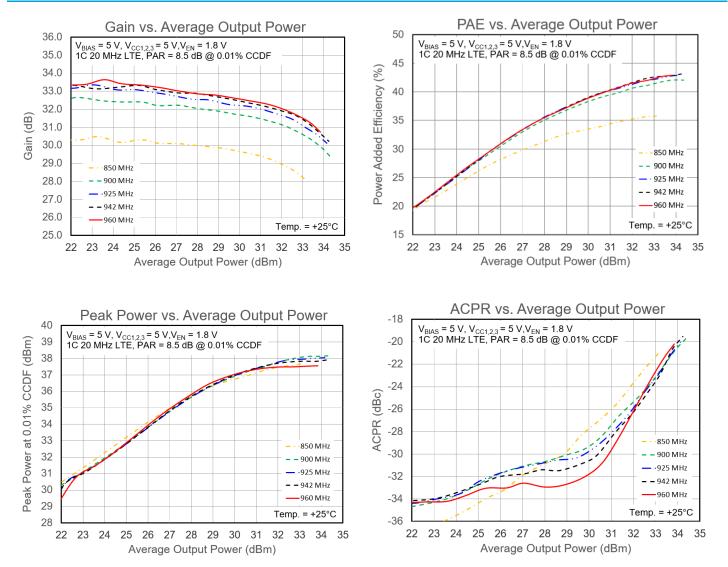
1. See Evaluation Board PCB Information for material and stack up.

Bill of Material – QPA9908EVB01

Reference Des.	Value	Description	Manuf.	Part Number
U1	-	Amplifier, QPA9908 850-960MHz, High-Efficiency	Qorvo	QPA9908
C1, C2	100 pF	CAP,100 pF, 0603, 5%, 50V, NPO	various	
C5, C9, C13, C17, C19	1000 pF	CAP,1000 pF, 0603, 5%, 50V, NPO	various	
C4, C8, C12, C18, C20	0.1 µF	CAP,0.1 µF, 0603, 10%, 50V, X7R	various	
C3, C7, C14	10 µF	CAP, 10 μF, 1206, 16V	various	
L1, L2	0 Ω	RES 0 Ω, 0603, 1/16W, Chip	various	

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Performance Plots – LTE

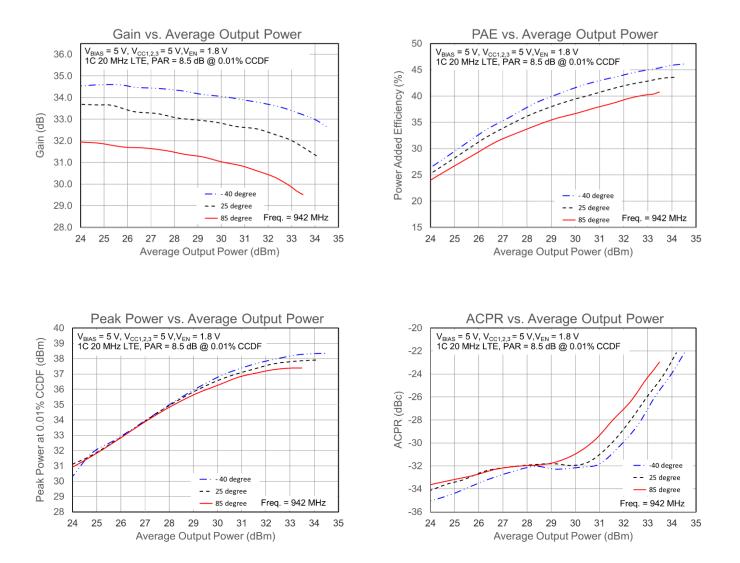


Test conditions unless otherwise noted: $V_{BIAS} = 5 V$, $V_{CC1,2,3} = 5 V$, $V_{EN} = 1.8 V$, $T = +25^{\circ}C$, tested using a single-carrier, 20 MHz LTE signal with 8.5 dB PAR at 0.01% CCDF on a reference design fixture.

QONOD

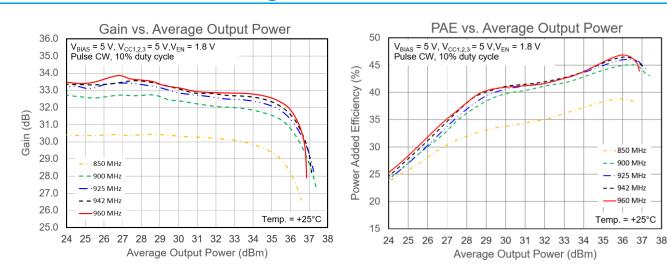
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Performance Plots – LTE



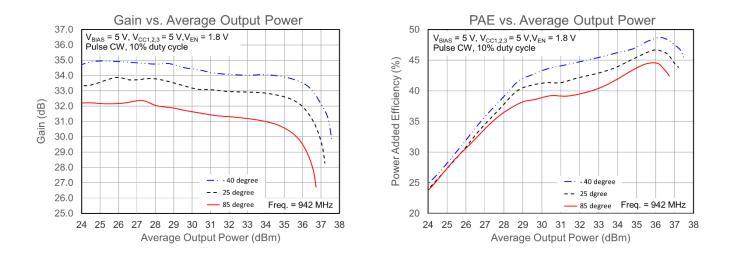
Test conditions unless otherwise noted: V_{BIAS} = 5 V, V_{CC1.2.3} = 5 V, V_{EN} = 1.8 V, tested at 942 MHz using a single-carrier, 20 MHz LTE signal with 8.5 dB PAR at 0.01% CCDF on a reference design fixture.

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Performance Plots – Pulsed Signal Measurements

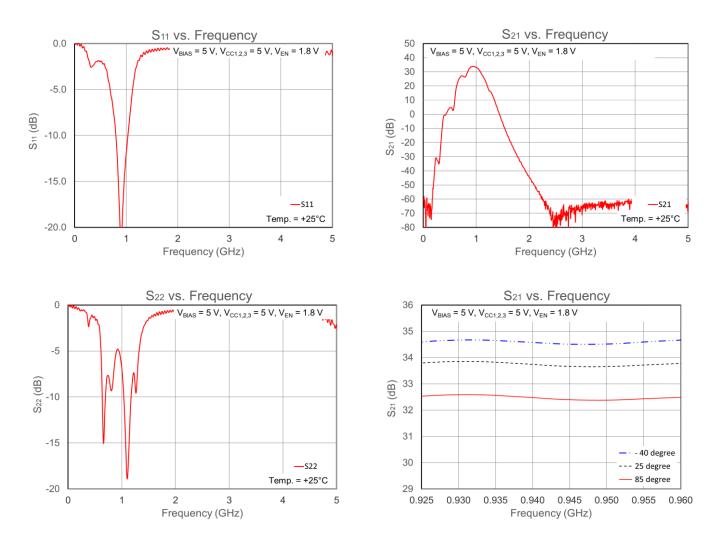
Test conditions unless otherwise noted: $V_{BIAS} = 5 V$, $V_{CC1,2,3} = 5 V$, $V_{EN} = 1.8 V$, $T = +25^{\circ}C$, tested using a pulse signal, 10% duty cycle.



Test conditions unless otherwise noted: V_{BIAS} = 5 V, V_{CC1,2,3} = 5 V, V_{EN} = 1.8 V, tested at 942 MHz using a pulse signal, 10% duty cycle.

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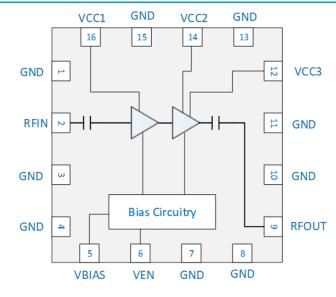
Performance Plots – S-parameter



Test conditions unless otherwise noted: $V_{BIAS} = 5 V$, $V_{CC1,2,3} = 5 V$, $V_{EN} = 1.8 V$.

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Pad Configuration and Description



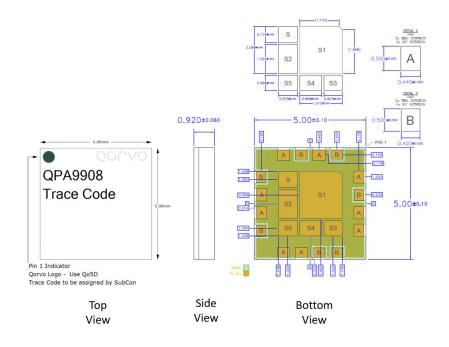
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Pad No.	Label	Description	
1, 3, 4, 7, 8, 10, 11, 13, 15	GND	Ground connection.	
2	RF _{IN}	RF input, internally matched to 50Ω .	
5	VBIAS	Bias circuit supply voltage	
6	V _{EN}	Amplifier enable voltage (regulated internally)	
9	RFout	RF output, internally matched to 50Ω . It has low impedance at DC. An external series capacitor is required if high impedance is needed at DC.	
12	V _{CC3}	Supply voltage for the various amplifier stages	
14	V _{CC2}	Supply voltage for the various amplifier stages	
16	V _{CC1}	Driver stage supply voltage	
Backside Paddle	GND	Ground connection. The back side of the package should be connected to the ground plan though as short of a connection as possible. PCB via holes under the device are recommended.	

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Package Marking and Dimensions

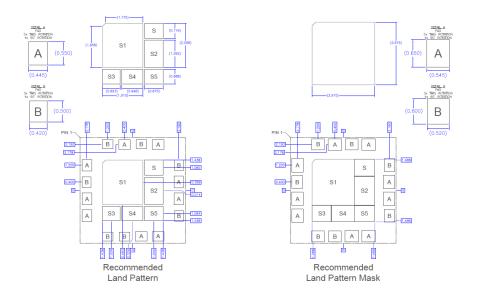
Marking: Pin 1 Indicator and Qorvo Logo



Notes:

- 1. All dimensions are in millimeters. Angles are in degrees.
- 2. The terminal #1 identifier and terminal numbering conform to JESD 95-1 SPP-012.
- 3. Contact plating: ENEPIG (Electroless Nickel Electroless Palladium Immersion Gold)

PCB Mounting Pattern

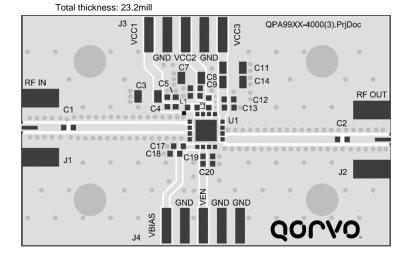


Evaluation Board PCB Information

PC Board Layout

Layer	Name	Material	Thickness	Constant
1	Top Overlay			
2	Top Solder	Solder Resist	0.40 mil	3.5
3	Top Layer	Copper	1.40 mil	
4	Dielectric1	RO4350	20.00 mil	3.48
5	Bottom Layer	Copper	1.40 mil	

PCB Material (stackup)



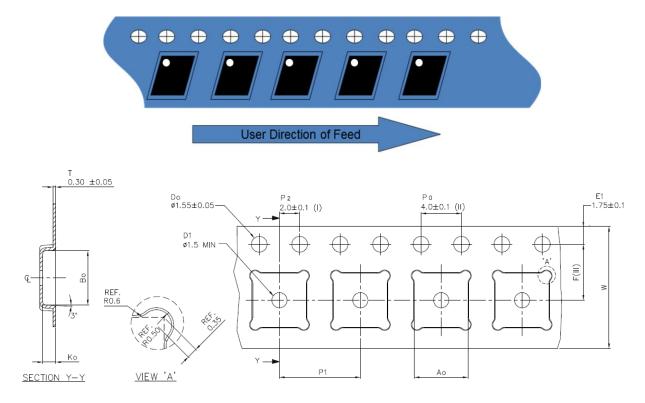
Notes:

- 1. All dimensions are in millimeters. Angles are in degrees.
- 2. Use 1 oz. copper minimum for top and bottom layer metal.
- 3. Via holes are required under the backside paddle of this device for proper RF/DC grounding and thermal dissipation. We recommend a 0.35mm (#80/.0135") diameter bit for drilling via holes and a final plated thru diameter of 0.25 mm (0.10").
- 4. Ensure good package backside paddle solder attach for reliable operation and best electrical performance.

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Tape and Reel Information – Carrier and Cover Tape Dimensions

Tape and reel specifications for this part are also available on the Qorvo website. Standard T/R size = 2500 pieces on a 13° reel.

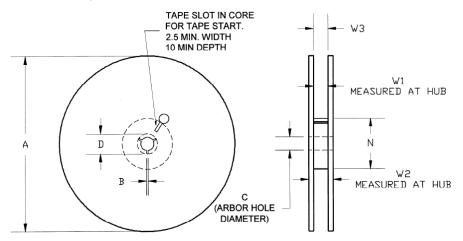


Feature	Measure	Symbol	Size (in)	Size (mm)
	Length	A0	0.209	5.3
Covity	Width	B0	0.209	5.3
Cavity	Depth	K0	0.051	1.3
	Pitch	P1	0.315	8.0
Centerline Distance	Cavity to Perforation - Length Direction	P2	0.079	2.0
Centenine Distance	Cavity to Perforation - Width Direction	F	0.217	5.5
Cover Tape	Width	С	0.362	9.2
Carrier Tape	Width	W	0.472	12

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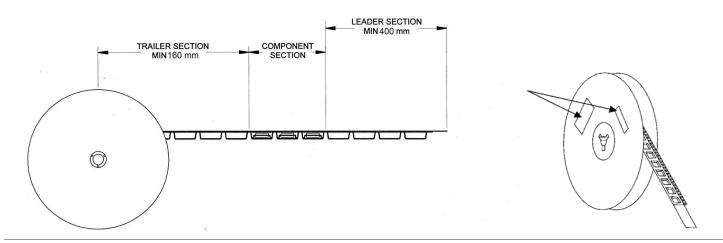
Tape and Reel Information – Reel Dimensions

Packaging reels are used to prevent damage to devices during shipping and storage, loaded carrier tape is typically wound onto a plastic take-up reel. The reel size is 13" diameter. The reels are made from high-impact injection-molded polystyrene (HIPS), which offers mechanical and ESD protection to packaged devices.



Feature	Measure	Symbol	Size (in)	Size (mm)
	Diameter	A	12.992	330.00
Flange	Thickness	W2	0.717	18.20
	Space Between Flange	W1	0.504	12.80
Hub	Outer Diameter	N	4.016	102.00
	Arbor Hole Diameter	С	0.512	13.00
	Key Slit Width	В	0.079	2.00
	Key Slit Diameter	D	0.795	20.2

Tape and Reel Information – Tape Length and Label Placement

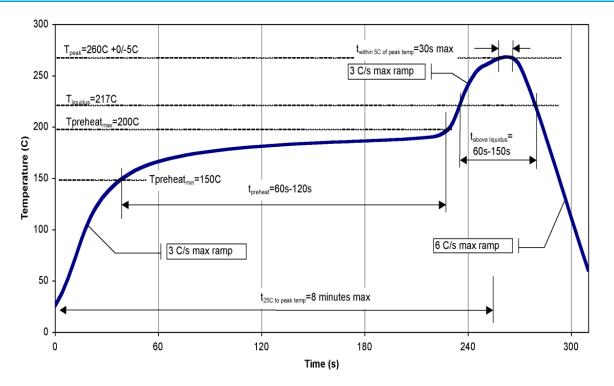


Notes:

- 1. Empty part cavities at the trailing and leading ends are sealed with cover tape. See EIA 481.
- 2. Labels are placed on the flange opposite the sprockets in the carrier tape.

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Recommended Solder Temperature Profile



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Handling Precautions

Parameter	Rating	Standard	
ESD-Human Body Model (HBM)	1C	ESDA/JEDEC JS-001-2012	Caution! ESD-Sensitive Device
ESD-Charged Device Model (CDM)	C3	JEDEC JESD22-C101F	
MSL-Moisture Sensitivity Level	3	IPC/JEDEC J-STD-020	

Solderability

Compatible with both lead-free (260°C max. reflow temp.) and tin/lead (245°C max. reflow temp.) soldering processes. Solder profiles available upon request.

Contact plating: ENEPIG (Electroless Nickel Electroless Palladium Immersion Gold)

RoHS Compliance

This part is compliant with 2011/65/EU RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment) as amended by Directive 2015/863/EU.

This product also has the following attributes:

- Product uses RoHS Exemption 7c-I to meet RoHS Compliance requirements.
- Halogen Free (Chlorine, Bromine)
- Antimony Free
- TBBP-A (C15H12Br402) Free
- PFOS Free
- SVHC Free

Contact Information

For the latest specifications, additional product information, worldwide sales and distribution locations:

Web: www.qorvo.com

Tel: 1-844-890-8163

Email: <u>customer.support@gorvo.com</u>

For technical questions and application information:

Email: appsupport@gorvo.com

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